

### 1.0 SCOPE

This specification documents the detailed requirements for Analog Devices space qualified die including die qualification as described for Class K in MIL-PRF-38534, Appendix C, Table C-II except as modified herein.

The manufacturing flow described in the STANDARD DIE PRODUCTS PROGRAM brochure at <http://www.analog.com/aerospace> is to be considered a part of this specification.

This data sheet specifically details the space grade version of this product. A more detailed operational description and a complete data sheet for commercial product grades can be found at [www.analog.com/DAC08](http://www.analog.com/DAC08)

### 2.0 Part Number. The complete part number(s) of this specification follow:

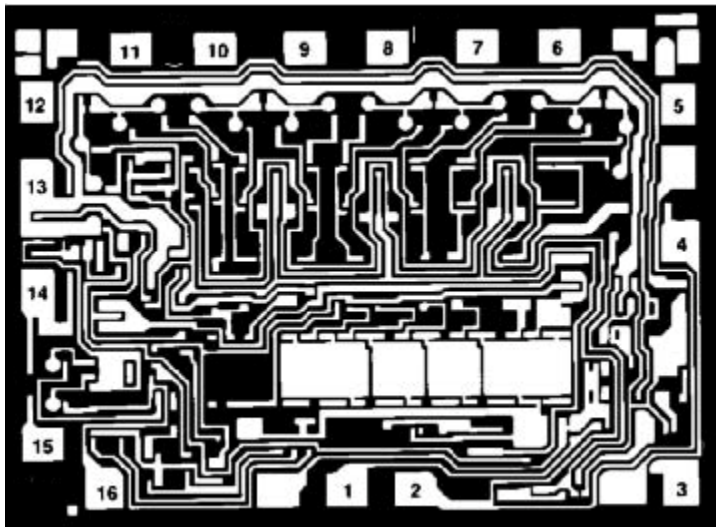
Part Number	Description
DAC08-000C	8-Bit High-Speed Multiplying D/A Converter
DAC08R000C	Radiation guaranteed 8-Bit High-Speed Multiplying D/A Converter

### 3.0 Die Information

#### 3.1 Die Dimensions

Die Size	Die Thickness	Bond Pad Metalization
63 mil x 87 mil	19 mil ± 2 mil	Al/Cu

#### 3.2 Die Picture



1.  $V_{LC}$
2.  $\overline{I_{OUT}}$
3.  $V^-$
4.  $I_{OUT}$
5. B1 (MSB)
6. B2
7. B3
8. B4
9. B5
10. B6
11. B7
12. B8 (LSB)
13.  $V^+$
14.  $V_{REF+}$
15.  $V_{REF-}$
16. COMP

ASD0012821

Rev. G

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# DAC08

## 3.3 Absolute Maximum Ratings <sup>1/</sup>

Supply Voltage (V+ to V-) .....	36V dc
Logic Inputs .....	V- to (V- plus 36V dc)
Logic Control Voltage (V <sub>LC</sub> ) .....	V- to V+
Analog Current Outputs (at V- = 15V) .....	4.25mA
Reference Input (V <sub>REF+</sub> to V <sub>REF-</sub> ) .....	V- to V+
Reference Input Differential Voltage (V <sub>REF+</sub> to V <sub>REF-</sub> ) .....	±18V dc
Reference Input current (I <sub>VREF+</sub> ) .....	5mA
Storage Temperature Range .....	-65°C to +125°C
Ambient Operating Temperature Range (T <sub>A</sub> ) .....	-55°C to +125°C
Junction Temperature (T <sub>J</sub> ).....	+150°C

Absolute Maximum Ratings Notes:

- <sup>1/</sup> Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

## 4.0 Die Qualification

In accordance with class-K version of MIL-PRF-38534, Appendix C, Table C-II, except as modified herein.

- (a) Qual Sample Size and Qual Acceptance Criteria – 25/2
- (b) Qual Sample Package – DIP
- (c) Pre-screen electrical test over temperature performed post-assembly prior to die qualification.

Table I - Dice Electrical Characteristics					
Parameter	Symbol	Conditions 1/	Limit Min	Limit Max	Units
Power Supply	I+	$V_S = \pm 15V; I_{REF} \leq 2mA$		3.8	mA
	I-		-7.8		
Full Range Current	$I_{FR}$	$V_{REF} = 10V,$ $R_{14}, R_{15} = 5k\Omega$	1.94	2.04	mA
Output Voltage Compliance	$V_{OC}$	Full Range Current Change < 1/2 LSB	-10	18	V
Zero Scale Current	$I_{ZS}$			2	$\mu A$
Full Range Symmetry	$I_{FRS}$	$I_{FR} - \overline{I_{FR}}$		$\pm 8$	$\mu A$
Output Current Range	$I_{OR1}$	$V_{REF} = 15V, V_- = -10V,$ $R_{14}, R_{15} = 5k\Omega$	2.1		mA
	$I_{OR2}$	$V_{REF} = 25V, V_- = -12V,$ $R_{14}, R_{15} = 5k\Omega$	4.2		
Power Supply Sensitivity	$PSSI_{FS+}$	$V_+ = 4.5V \text{ to } 18V,$ $V_- = -18V; I_{REF} = 1mA$		$\pm 0.01$	$\frac{\% \Delta I_O}{\% \Delta V_+}$
	$PSSI_{FS-}$	$V_- = -4.5V \text{ to } -18V,$ $V_+ = +18V; I_{REF} = 1mA$		$\pm 0.01$	$\frac{\% \Delta I_O}{\% \Delta V_-}$
Reference Bias Current	$I_{VREF-}$		0	-3	$\mu A$
Logic Input Levels	$V_{IL}$	Logic "0", $V_{LC} = 0V$		0.8	V
	$V_{IH}$	Logic "1", $V_{LC} = 0V$	2		
Logic Input Current (Each Bit)	$I_{IL}$	$V_{IN} = -10V, V_{LC} = 0V$		-10	$\mu A$
	$I_{IH}$	$V_{IN} = 18V, V_{LC} = 0V$		+10	
Logic Input Swing	$V_{IS}$	$I_{FR} = 1.94mA \text{ (min)}$ $I_{FR} = 2.04mA \text{ (max)}$	-10	+18	V
Resolution			8		Bits
Monotonicity			8		Bits
Nonlinearity	NL			$\pm 0.1$	%FS

Table I Notes:

- $V_S = \pm 15V, I_{REF} = 2mA,$  and  $T_A = +25^\circ C,$  unless otherwise specified.

**Table II - Electrical Characteristics for Qualification**

Parameter	Symbol	Conditions 1/	Sub-groups	Limit Min	Limit Max	Units
Power Supply 2/	I+	$V_S = \pm 15V$ or $+5V, -15V$	1, 2, 3		3.8	mA
		$V_S = \pm 5V, I_{REF} = 1mA$				
		M, D, L, R			4.0	
	I-	$V_S = \pm 15V$ or $+5V, -15V$	1, 2, 3	-7.8		
		$V_S = \pm 5V; I_{REF} = 1mA$	1, 2, 3	-5.8		
	M, D, L, R 3/	1	-8.0			
Full Range Current	I <sub>FR</sub>	$V_{REF} = 10V,$ $R_{14}, R_{15} = 5k\Omega$	1, 2, 3	1.94	2.04	mA
		M, D, L, R 3/	1	1.925	2.04	
Output Voltage Compliance 4/	V <sub>OC</sub>	Full-Scale Current Change < 1/2 LSB	1, 2, 3	-10	+18	V
Zero Scale Current	I <sub>ZS</sub>		1, 2, 3		2	μA
		M, D, L, R 3/	1		2	
Full Range Symmetry 4/	I <sub>FRS</sub>	$I_{FR+} - I_{FR-}$	1, 2, 3		±8	μA
Output Current Range 4/	I <sub>OR1</sub>	$V_{REF} = 15V, V_- = -10V;$ $R_{14}, R_{15} = 5k\Omega$	1, 2, 3	2.1		mA
	I <sub>OR2</sub>	$V_{REF} = 25V, V_- = -12V;$ $R_{14}, R_{15} = 5k\Omega$		4.2		
Power Supply Sensitivity 4/	PSSI <sub>FS+</sub>	$V_+ = 4.5V$ to 18V, $V_- = -18V, I_{REF} = 1mA$	1, 2, 3		±0.01	$\frac{\% \Delta I_O}{\% \Delta V_+}$
	PSSI <sub>FS-</sub>	$V_- = -4.5V$ to -18V, $V_+ = 18V, I_{REF} = 1mA$			±0.01	$\frac{\% \Delta I_O}{\% \Delta V_-}$
Reference Bias Current 4/	I <sub>VREF-</sub>		1, 2, 3	0	-3	μA
Logic Input Levels	V <sub>IL</sub>	Logic "0", V <sub>LC</sub> = 0V	1, 2, 3		0.8	V
		M, D, L, R 3/	1		0.8	
	V <sub>IH</sub>	Logic "1", V <sub>LC</sub> = 0V	1, 2, 3	2.0		
		M, D, L, R 3/	1	2.0		
Logic Input Current (Each Bit) 4/	I <sub>IL</sub>	V <sub>IN</sub> = -10V, V <sub>LC</sub> = 0V	1, 2, 3		-10	μA
		M, D, L, R 3/	1		-30	
	I <sub>IH</sub>	V <sub>IN</sub> = 18V, V <sub>LC</sub> = 0V	1, 2, 3		10	
		M, D, L, R 3/	1		10	
Logic Input Swing 4/	V <sub>IS</sub>	I <sub>FR</sub> = 1.94mA (min) I <sub>FR</sub> = 2.04mA (max)	1, 2, 3	-10	+18	V
Monotonicity 4/			1, 2, 3	8		Bits
Nonlinearity	NL		1, 2, 3		±0.19	%FS
		M, D, L, R 3/	1		±0.45	
Full Scale Tempco 4/	TCl <sub>FS</sub>		8		±80	ppm/°C

Table II Notes:

1.  $V_S = \pm 15V, I_{REF} = 2mA$ , unless otherwise specified.
2. When the device is used in an un-biased state at high temperature only, and subsequently biased, the device supply currents may rise 30% above specification for as long as 30 seconds.
3. Devices tested at 100K.
4. This parameter not tested post irradiation.

Table III - Life Test Endpoint and Delta Parameter (Product is tested in accordance with Table II with the following exceptions)								
Parameter	Symbol	Sub-groups	Post Burn In Limit		Post Life Test Limit		Life Test Delta	Units
			Min	Max	Min	Max		
Full Range Current	$I_{FR}$	1	1.93	2.05	1.92	2.06	0.01	mA
	$\overline{I_{FR}}$							
Zero Scale Current	$I_{ZS}$	1		2.5		3	0.5	$\mu$ A
	$\overline{I_{ZS}}$							

## 5.0 Life Test/Burn-In Information

- 5.1 HTRB is not applicable for this drawing.  
 5.2 Burn-in is per MIL-STD-883 Method 1015 test condition B or C.  
 5.3 Steady state life test is per MIL-STD-883 Method 1005.

Rev	Description of Change	Date
A	Initiate	20-DEC-01
B	Update web address	Aug. 5, 2003
C	Add radiation limits same as SMD	Aug. 25, 2003
D	Update header/footer & add to 1.0 Scope description.	March 3, 2008
E	Add Junction Temperature ( $T_j$ ) ...+150°C to Absolute Max. Ratings	April 2, 2008
F	Updated Section 4.0c note to indicated pre-screen temp testing being performed.	June 6 2009
G	Update fonts and sizes to ADI standards	Nov. 15, 2011